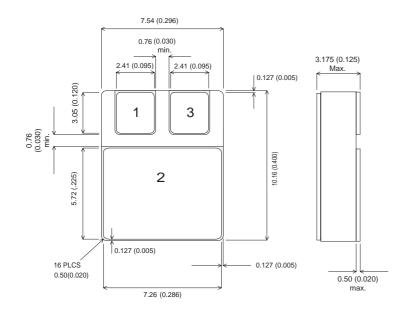


IRFNJ9130 IRF9130SMD05

MECHANICAL DATA

Dimensions in mm (inches)



SMD05 (TO-276AA)

IRF9130SMD05

PAD1 = GATE PAD 2 DRAIN PAD3 = SOURCE

IRFNJ9130

PAD1 = SOURCE PAD 2 = DRAIN PAD3 = GATE

P-CHANNEL POWER MOSFET FOR HI-REL APPLICATIONS

 V_{DSS} -100V $I_{D(cont)}$ -11A $R_{DS(on)}$ 0.30 Ω

FEATURES

- HERMETICALLY SEALED
- SIMPLE DRIVE REQUIREMENTS
- LIGHTWEIGHT
- SCREENING OPTIONS AVAILABLE
- ALL LEADS ISOLATED FROM CASE

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

V_{GS}	Gate – Source Voltage	±20V
I_D	Continuous Drain Current @ T _{case} = 25°C	-11A
I_D	Continuous Drain Current @ T _{case} = 100°C	-7A
I_{DM}	Pulsed Drain Current	-50A
P_{D}	Power Dissipation @ T _{case} = 25°C	45W
	Linear Derating Factor	0.36W/°C
T_J , T_stg	Operating and Storage Temperature Range	−55 to 150°C
$R_{\theta JC}$	Thermal Resistance Junction to Case	2.8°C/W max.

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455) 556565. Fax +44(0)1455) 552612.

Document Number 5544

E-mail: sales@semelab.co.uk Website http://www.semelab.co.uk



IRFNJ9130 IRF9130SMD05

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise stated)

	Parameter	Test Cond	Min.	Тур.	Max.	Unit	
	STATIC ELECTRICAL RATINGS			•			
BV _{DSS}	Drain – Source Breakdown Voltage	$V_{GS} = 0$	$I_D = -1mA$	-100			V
ΔBV_{DSS}	Temperature Coefficient of	Reference to 2	25°C		-0.1		V/°C
ΔT_{J}	Breakdown Voltage	$I_D = -1 \text{mA}$			-0.1		
R	Static Drain - Source On-State	V _{GS} = -10V	I _D = -7A			0.30	Ω
R _{DS(on)}	Resistance	V _{GS} = -10V	I _D = -11A			0.35	32
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$	I _D = -250μA	-2		-4	V
9 _{fs}	Forward Transconductance	V _{DS} ≥ -15V	$I_{DS} = -7A$	3			S(\Omega)
lana	Zero Gate Voltage Drain Current	$V_{GS} = 0$	$V_{DS} = -80V$			-25	μΑ
I _{DSS}	Zero Gate Voltage Brain Garrent		$T_J = 125$ °C			-250	
I _{GSS}	Forward Gate – Source Leakage	$V_{GS} = -20V$				-100	nA
I _{GSS}	Reverse Gate – Source Leakage	V _{GS} = 20V				100	
	DYNAMIC CHARACTERISTICS						
C _{iss}	Input Capacitance	$V_{GS} = 0$			860		
C _{oss}	Output Capacitance	$V_{DS} = 25V$			350		pF
C _{rss}	Reverse Transfer Capacitance	f = 1MHz			125		
Qg	Total Gate Charge	V _{GS} = -10V				29	
Q _{gs}	Gate - Source Charge	$V_{DS} = -50V$				7.1	nC
Q _{gd}	Gate - Drain ("Miller") Charge	I _D = -11A				21	
t _{d(on)}	Turn-On Delay Time	V _{DD} = -50V				60	
t _r	Rise Time	I _D = -11A				140	ns
t _{d(off)}	Turn-Off Delay Time	$R_G = 7.5\Omega$				140	1 113
t _f	Fall Time					140	
	SOURCE - DRAIN DIODE CHARAC	TERISTICS					
I _S	Continuous Source Current					-11	Α
I _{SM}	Pulse Source Current					-50	^
Von	Diode Forward Voltage	I _S = -11A	$T_J = 25^{\circ}C$			-4.7	V
V _{SD}	Diode i diward voltage	$V_{GS} = 0$				-4.1	v
t _{rr}	Reverse Recovery Time	I _S = -11A	$T_J = 25^{\circ}C$			250	ns
Q _{rr}	Reverse Recovery Charge	$\int d_i / d_t \le -100A$	/μs V _{DD} ≤ 150V			3	μС

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Semelab plc. Telephone +44(0)1455) 556565. Fax +44(0)1455) 552612. E-mail: sales@semelab.co.uk Website http://www.semelab.co.uk



HIGH RELIABILITY and SCREENING OPTIONS

S E M E L A B PLC

Contents

1.	Introduction	1
2.	Quality Approvals	2
3.	Material Qualification	3
	3.1 Header/Cap/Wire Approval Procedures	3
	3.2 Die Approval Procedure	
4	CECC (Discrete Products)	5
٠.	4.1 Inspection Levels for CECC Fully Assessed Devices	
	4.2 CECC Screening Options	
5.	BS (Linear Products)	8
	5.1 Inspection Levels for BS Fully Assessed Devices	8
	5.2 BS Screening Options (Linear IC's)	. 10
6.	DSCC / 883B (Linear Products)	.11
	6.1 Inspection Levels for DSCC SMD listed Devices	
	6.2 Screening Sequence for DSCC SMD listed devices	
7	ESA - ESCC - Space Level Products	1/
٠.	7.1 Chart F2 - Production Control	
	7.1 Chart F2 - Production Control	
	7.3 Chart F4 - Qualification and Periodic Tests	
8.	Semelab In-House Processing Options	
	8.1 CECC processed devices (QR208, QR209)	
	8.2 BS and CV processed devices (Bipolar)	
	8.3 MIL-PRF-19500 Processed Discrete Semiconductors (QR205, QR204)	
	8.3.1 QR205 - Inspection levels: 'Mil Processed' Quality Conformance	
	8.3.2 QR204 - Screening Sequences 'Mil Processed' Components	
	8.4 Space Level Processed Discrete Semiconductors (QR216, QR217)	
	8.4.2 QR216 - Screening: Space Level Processed' Components	
	8.4.3 Comparison of space level die lot approval	
	8.5 MIL-883B Processed Integrated Circuits (QR214, QR215)	
	8.6 Customer Specifications	
	8.7 Data Sheets	
0	Comparison of Saraaning Options	20
J .	Comparison of Screening Options	
	9.1 Comparison Hi-Rel Screening options	
	3.2 COMDANSON OF SDACE LEVEL SCIECHING UDITONS	30

1. Introduction

Experience and Innovation In Semiconductor Technology

At SEMELAB, we research, design, manufacture and distribute an innovative range of semiconductor products throughout the world.

Our R&D teams have an excellent track record for developing imaginative electronic solutions. Our design engineers have created a wealth of high performance products. Our manufacturing divisions have ensured supreme quality and reliability. And our sales teams and distribution partners have opened international markets to some of the best electronics solutions available.

We hold all the necessary Qualification Approvals needed to serve the Military and Hi-Rel Industries now including **QML** Approval for a series of **Linear Integrated Circuits** and **QML** Approval for our laboratory test house capabilities. The test facilities are available to qualify and screen third party products, including Hybrid products not made by the Group. We have the ability and considerable experience of most test methods currently demanded.

We specialise in the fabrication of very high quality products especially intended for use in high reliability applications. We have supplied many millions of discrete and linear integrated circuits into all forms of high reliability equipment such as:

•	Space	Satellite Vehicles
---	-------	--------------------

Launchers

Support & defence

Aircraft Military

Civil

Air Traffic Control

• Communications Secure Communication Links

Military links Naval Links

Broadcast Transmitters
Underwater Repeaters

Defence Guided weapons

Electronic Counter Measures

Command & Control

Radar

Transportation
 Railway Signalling Systems

Traction Systems

Automatic Signalling Systems

Harsh Environment
 Oil Rig Installations

Drill Head Sensors Atomic Event Detectors

This is SEMELAB: design innovation, backed by numerous approvals and manufacturing strength and **led by a total commitment to quality**.

1

⁻⁻⁻ everywhere when there is a need for cost effective ultra reliable products.

2. Quality Approvals

SCHEME	Description	SML Facilities Approval (Y/N)	SEMELAB Approval No	SML Devices Types Approved	Remarks
Current Schemes					
BS9000	British Standards for Linear ICs and Discrete Semiconductors	Y detailed approval for many products	1360/M	Linear ICs and Discrete Semiconductors	Replaced in many areas by CECC or DSCC. Approved suppliers and products listed in PD9002
BS EN ISO 9001:2000	International Standard for Quality Assurance management of all phases in the provision of goods and services. Replaces most of the old "national" systems.	Y	FM36235	refers to all product types	The whole Semelab facility and all products conform with these norms.
CECC 50000	European Military Quality Approval system for Discrete Semiconductors	Y detailed approval for many products	M/0103/CECC/ UK-1181M	Small signal discretes, Power discretes	European QPL. Generally in decline
CECC 90000	European Military Quality Approval system for ICs.	Y detailed approval for many products	M/0103/CECC/ UK-1181M	Linear ICs.	European QPL. Generally in decline
DSCC QPL approval	US Manufacturing approval accepted everywhere	Y detailed approval for large range of linear ICs.	Cage NO. U3158	Linear ICs	Detailed product approval by DSCC - e.g. commonly called MIL/883B for linear ICs
DSCC QML approval	US Manufacturing approval accepted everywhere	Y	DSCC -VQ-03- 003050 & DSCC-VQ-03-	Linear ICs (level Q certification) Laboratory Suitability	Will generally replace many of the older approval systems on International Military Systems.
ESA ESCC FOOD	European Chase Agency	Y	003049 QPL No 253	2N2880 - more to	Draduct built & cumplied in accordance
ESA - ESCC 5000, SCC 9000	European Space Agency	T	QPL N0 253	follow	Product built & supplied in accordance with generic ESCC specifications
STANAG 4093	General reciprocal listing arrangement	Y		All product types	Reciprocal QPL listing between Europe and North America
Schemes being phased out					
AQAP-1	Applies in UK and related areas. Replaced Defence Standard 05/21	Y	MOD Registration No.2M8S02		Being superseded by BS/EN/ISO 9001
GAMT1	French Military approved products list	Y detailed approval for many products		A large number	French Market - should be replaced by BS/EN/ISO9001
MUAHAG	European - Military users and Harmonisation Advisory Group	Y detailed approval for many products		Discrete products - volume 9. Linears - volume 7	Components generally for European Military equipment makers - should be replaced by BS/EN/ISO9001
NATO	NATO system applies to NATO systems	Y listed for many products	Manufacturer Code 3158	Several hundred discrete products	Tending towards being a legacy system now
Legacy Schemes					
CV	Very early UK approvals system for Military and GPO types	y some parts replaced by BS types, CECC or CVxxxx-0 parts			Legacy system - generally replaced by BS or CECC types
DEF Specs	Precursor of Defence Standard Specifications	Many types - all built to order.			Replaced by Defence Standard Specifications. Generally already phased out.
Defence Standards (many)	Relate to materials, components and processes for UK Military use	Y for many products but under AQAP1 and ISO9001		Discrete products	Legacy system little used now. The most common DEF Stan relating to Semiconductors is DEF STAN 05/21 - replaced by AQAP1
RRE, RSRE P & SRDE Specifications	Specifications drawn up in support of MOD projects	Y for many types		Discrete products	Legacy system little used now.

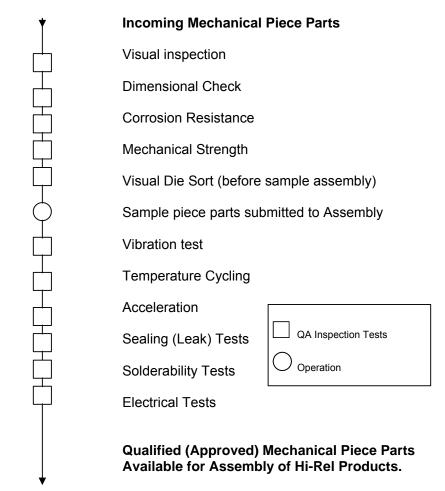
2. Material Screening

Piece Part – Qualification and pre-assembly approval process flow.

Before contemplating the assembly of any qualified semiconductor product, it is essential that all the materials used in the construction of the parts be obtained from fully qualified and trustworthy suppliers - those with a long continuous and successful supply history. Little used or untried or suspect materials are thoroughly checked and qualified as being suitable for their intended application before use.

In this case, mechanical piece parts are subject to an exhaustive series of tests culminating in sample assemblies being built to establish lack of flaws and lack of unwanted difficulties during assembly.

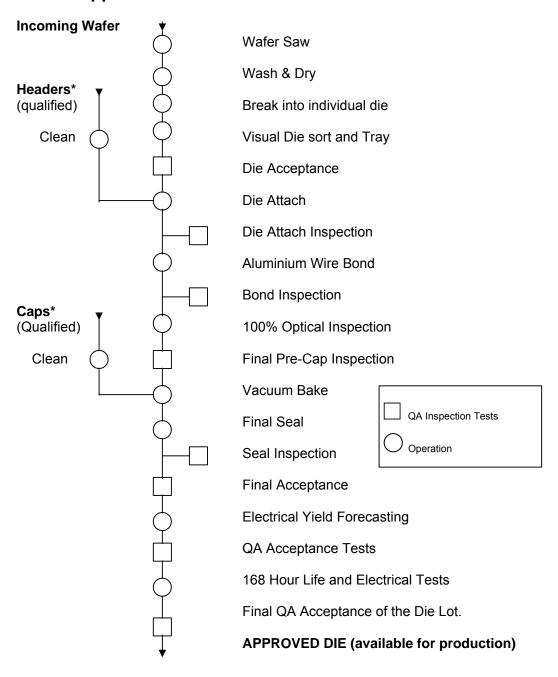
3.1 Header / Cap / Wire Approval Procedures



Notes: Approval procedures are performed on samples to approve each single lot of material.

Each batch of assembled piece parts carries its own unique "date" code. Traceability to each incoming batch of materials (all mechanical batches and die lots) is guaranteed from this unique number.

3.2 Die Approval Procedure



Each batch of assembled piece parts carries its own unique "date" code. Traceability to each incoming batch of materials (all mechanical batches and die lots) is guaranteed from this unique number.

The die qualification can include a 1000-hour electrical endurance test. One of the major objectives is to ensure that the die lot's performance stabilises rapidly during the initial portion of this period and then remain unchanged throughout the remainder of the test (and life).

Die and mechanical piece parts intended for use in Ultra-Reliable applications e.g. Space Vehicles are subject to more rigorous evaluation.

4. CECC (Discrete Devices)

Registration: M/0103/CECC/UK

SEMELAB offers one of the largest ranges of CECC approved products in Europe, including small signal and power devices. These devices have undergone approval for use in new applications as well as providing continuing support for existing applications.

All piece parts used in the manufacture of CECC released products undergo stringent qualification procedures before they can be used. For further details contact our Quality Manager (qa@semelab.co.uk).

Full forward and backward traceability is maintained on all CECC released devices

All CECC fully assessed devices are subject to groups A, B and C inspection carried out in the Quality Assurance Department in Lutterworth. Assessment is available to levels E, F & L.

Ordering Information (example):-

BDS18CECC full assessment level (without additional screening)
BDS18CECC-B CECC full assessment level + sequence B screen

4.1 Inspection Levels for CECC Fully Assessed Devices

Group A - Lot by lot inspection

IL = inspection levels
AQL = Acceptable Quality Level (%)

	Levels of Quality Assessment								
Examination or test			Level E	Level F & Level L					
	IL	AQL	Observations		AQL	Notes			
SUB-GROUP A1 Visual Inspection	I	0.65		ı	0.65				
SUB-GROUP A2a Non operatives	II	0.15		II	0.15				
SUB-GROUP A2b Electrical Measurements	II	0.40	primary dc characteristics	II	0.65 1.0	$ if < 4 tests $ $ if \ge 4 tests $			
SUB-GROUP A3 Electrical Measurements	II	0.65	other dc characteristics	l I	2.5 4	if < 4 tests if ≥ 4 tests			
SUB-GROUP A4 Electrical Measurements	S4	1	ac characteristics	S4 S4	4 6.5	if < 4 tests if ≥ 4 tests			

5

CECC (Discrete Devices)

(continued)

Group B - Lot by lot inspection

IL = inspection level amb = ambient rated case = case rated
AQI in % c = acceptance criterion n = sample size

		AQL in 9	6 c = acce	ptance crite	rion n = sa	ample size			
	Levels of Quality Assessment								
Examination or test	Level E	Lev	el F	Le	vel L				
	n/c	IL	AQL	IL	AQL	Notes			
SUB-GROUP B1 Dimensions	15/0 or 25/1	S2	2.5	S2	2.5				
SUB-GROUP B2c Verification of ratings	15/0 or 25/1	S4	4	na	na	see C2c			
SUB-GROUP B3 Lead bending if applicable	15/0 or 25/1	S3	2.5	S2	4				
SUB-GROUP B4 Solderability	22/0 or 38/1	S4	2.5	S4	2.5				
SUB-GROUP B5 Change of temp followed by acc. Damp heat or sealing	15/0 or 25/1	S4	2.5	na	na	see C5			
SUB-GROUP B8 Electrical endurance	38/1 or 52/2	S4	1.5	na	na	see C8			
SUB-GROUP CTR	Unless otherwise stated in detail specification: attributes information for B3, B4, B5, B8								

Group C - Periodic Inspection

P = periodicity (months) na= not applied

	Levels of Quality Assessment									
Examination or test	E (p = 3 r	months)	F (p =	3 months)		L				
	n/c	notes	n/c	notes	Р	n/c	Notes			
SUB-GROUP C1 Dimensions	8/0 or 13/1		8/1		3	8/1				
SUB-GROUP C2a Electrical Measurements	15/0 or 25/1		13/1		3	13/1				
SUB-GROUP C2b Complementary characteristics	32/0 or 55/1 15/0 or 25/1	versus T versus I,V	18/1		3	18/1				
SUB-GROUP C2c Verification of ratings	15/0 or 25/1		13/1	when not in B2c	3	8/1				
SUB-GROUP C3 Tensile / Torque (if applicable)	15/0 or 25/1		8/1		6	8/1				
SUB-GROUP C4 Soldering heat	22/0 or 38/1		18/1		na	na				
SUB-GROUP C5 Change of temp followed by acc. Damp heat or sealing	na	see B5	na	see B5	3	13/1				
SUB-GROUP C6 Shock acceleration vibration	15/0 or 25/1		8/1		6	8/1				
SUB-GROUP C7 Damp heat (if applicable)	15/0 or 25/1		18/1		na	na				
SUB-GROUP C8 Electrical endurance	38/1 or 52/1		43/3 34/2	amb case	3	32/3 25/2	amb case			
SUB-GROUP C9 Storage at high temp	38/1 or 52/2		43/3 34/2	amb case	na	na				
SUB-GROUP CTR		otherwise sta , C5, C6, C9.		•						

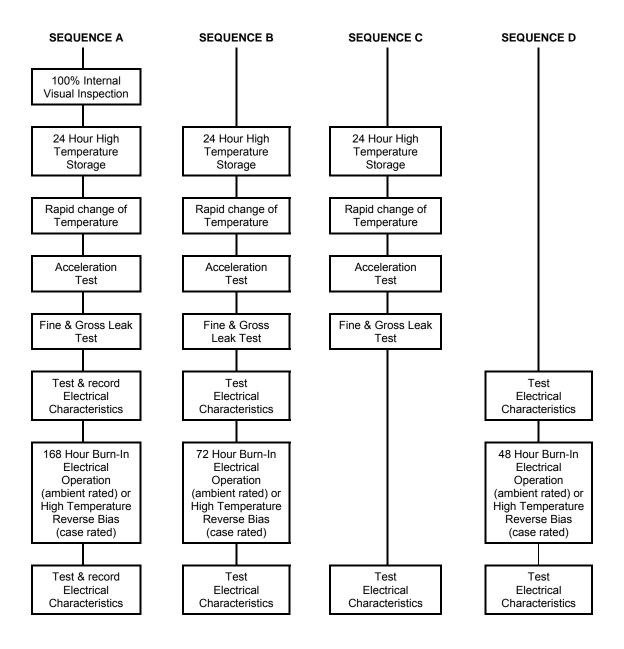
6

4.2 CECC Screening Options

All CECC approved devices can be supplied as a standard full assessment level part or with additional 100% screening to any of the four levels (A, B, C, D) in accordance to CECC 50000 Appendix VI

In addition, SEMELAB can supply screening on products where the full device approval does not exist or is not held. Screening is again carried out in accordance with any of the four levels within CECC 50000 Appendix VI and is carried out at our factory in Lutterworth.

Screening sequences are as laid out below:-



5. BS (Linear IC's)

Registration 1360/M.

SEMELAB offers a range of BS approved Linear IC's including Voltage regulators, PWM's and Control IC's. These families of devices have undergone approval for use in new applications in addition to providing continuing support for existing applications.

Full forward and backward traceability is maintained on all BS released devices

All BS fully assessed devices are subject to groups A,B,C and D inspection carried out in the Quality Assurance Department in Lutterworth. Screening is available to any of the four levels defined in BS9400 (S1, S2, S3, S4)

The generic specifications for these devices are as follows:

BS9400 IC's - Generic Data & Methods of Test

BS9430 Linear Voltage Regulators PWM and Control IC's

Ordering Information (example):-

IP117K-BSS2 BS full assessment level + category S2 screening

5.1 Inspection Levels for BS Fully Assessed Devices

Group A - Lot by lot inspection

IL = inspection levels
AQL = Acceptable Quality Level (%)

	Levels of Quality Assessment					
		1	Levels o	Quality Accessment		
Examination or test	IL	AQL	BS9400	Observations		
SUB-GROUP A1 Visual Inspection	ı	1.5	1.2.2			
SUB-GROUP A2						
Non operatives	II	0.15				
SUB-GROUP A3a Electrical Measurements	П	1.5		Static Characteristics Tamb=25°C		
SUB-GROUP A3b						
Electrical Measurements	П	1.5		Static Characteristics Tamb = Tmax		
SUB-GROUP A3c Electrical Measurements	II	1.5		Static Characteristics Tamb = Tmin		
SUB-GROUP A4a Electrical Measurements	S4	4%		Dynamic Characteristics Tamb = 25°C		

Group B - Lot by lot inspection

IL = inspection levels
AQL = Acceptable Quality Level (%)

	Levels of Quality Assessment				
Examination or test	IL	AQL	BS 9400	Observations	
SUB-GROUP B1 Dimensions	S2	6.5	1.2.3		
SUB-GROUP B2a Solderbility	S4	4.0	1.2.6.15.1		
SUB-GROUP B2b Change of temp followed by sealing	S4	4.0	1.2.6.13 1.2.6.14.1/2		
SUB-GROUP B3 Lead bending	S3	6.5	1.2.6.16.2		
SUB-GROUP B6 Acceleration steady state	S4	4.0	1.2.6.9		
SUB-GROUP B7 Electrical Endurance	S4	1.5	1.2.7.2.2		
SUB-GROUP B8 CTR Information			Unless otherwise stated in detail specification: attributes information for B2a, B2b, B6, B7		

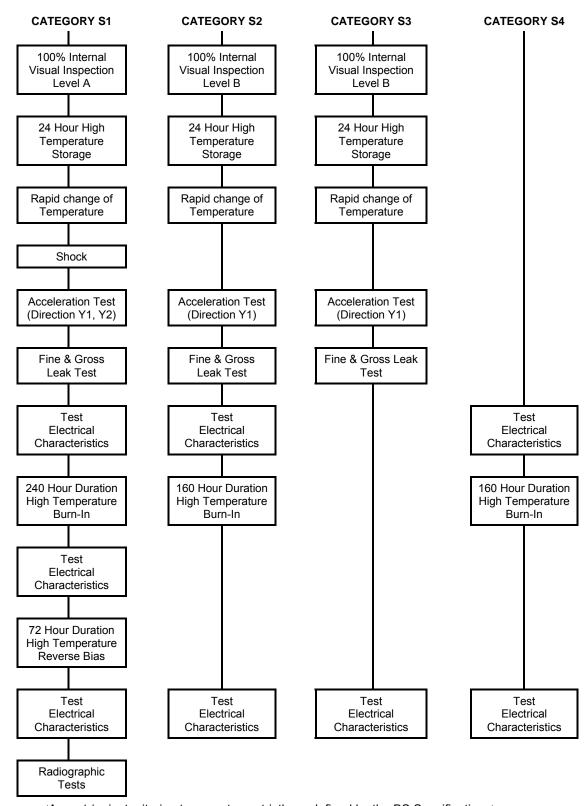
Group C - Periodic inspection

IL = inspection levels AQL = Acceptable Quality Level (%)

	Levels of Quality Assessment					
Examination or test	IL	AQL	BS 9400	Observations		
SUB-GROUP C1 Dimensions	S2	6.5	1.2.3			
SUB-GROUP C3 Vibration followed by Shock followed by Damp Heat Cycle	S2	6.5	1.2.6.8.1 1.2.6.6 1.2.6.5			
SUB-GROUP C5 Electrical Endurance	S3	4.0	1.2.7.2.2	Duration = 2000 hrs		
SUB-GROUP C6 CTR Information	S3	6.5	1.1.11	Unless otherwise stated in detail spec: attributes information for C3 & C5		

9

5.2 BS Screening Options (Linear IC's)



(Accept / reject criteria at every stage strictly as defined by the BS Specifications).

6. DSCC / 883B (Linear IC's) Built on Semelab's QML Qualified Production Lines.

Cage Number U3158

SEMELAB offers a range of DSCC SMD listed and 883B processed voltage regulators, PWM's and Control IC's. All manufacturing is carried out on our QML qualified lines in our Lutterworth factory to the appropriate MIL-STD-883 specifications (5005 - Processing and 5004 - Screening).

6.1 Inspection Levels for DSCC SMD Listed Devices

Method 5005: Table I Group A electrical tests for class level B

mounda occo.	Table I Gleap /	t olootilloal to	oto for diago level B
Examination or test	t	Quality/accept	Observations
SUB-GROUP 1	Static Tests	116/0	Tamb = 25°C
SUB-GROUP 2	Static Tests	116/0	Tamb = Tmax
SUB-GROUP 3	Static Tests	116/0	Tamb = Tmin
SUB-GROUP 4	Dynamic Tests	116/0	Tamb = 25°C
SUB-GROUP 5	Dynamic Tests	116/0	Tamb = Tmax
SUB-GROUP 6	Dynamic Tests	116/0	Tamb = Tmin
SUB-GROUP 7	Functional Tests	116/0	Tamb = 25°C
SUB-GROUP 8a	Functional Tests	116/0	Tamb = Tmax
SUB-GROUP 8b	Functional Tests	116/0	Tamb = Tmin
SUB-GROUP9	Switching tests	116/0	Tamb = 25°C
SUB-GROUP10	Switching tests	116/0	Tamb = Tmax
SUB-GROUP11	Switching tests	116/0	Tamb = Tmin

¹⁾ The specific parameters to be included for tests in each subgroup shall be as specified in the applicable acquisition document. Where no parameters have been identified in a particular subgroup or tests within a subgroup, no group A testing is required for that subgroup or test to satisfy group A requirements.

Method 5005: Table IIb Group B tests for class level B

Test	note	MIL-STD-883 method	Condition		Quantity/accept or sample size/accept
Subgroup 2 Resistant to solvents	(3)	2015			3/0
Subgroup 2 Solderability	(4)	20 03	temp 245°C ± 5°C	soldering	sample size number = 22, c = 0
Subgroup 3 Bond strength 1) Thermo-compression 2) Ultrasonic / Wedge 3) Flip-chip 4) Beam lead	(5)	2011	1) Test Condition C or D 2) Test Condition C or D 3) Test Condition F 4) Test Condition H		sample size number = 15, c = 0

³⁾ Resistance to solvents testing required only on devices using inks or paints as the marking or contrast.

11

²⁾ When the (sub)lot size is less than the required sample size, each and every device in the (sub)lot shall be inspected and all failed devices removed from the (sub)lot for final acceptance of that test, subgroup, or set of tests/subgroups.

⁴⁾ Devices submitted for solderability shall be in the same lead finish as shipped product and must have been through the temp/time exposure of burn in except for devices which have been hot solder dipped or have lead-tin fusing after burn-in.

⁵⁾ Unless otherwise specified the sample size number for condition C or D is the number of bond pulls selected from a minimum number of 4 devices and for condition F or H is the number of dice (not bonds).

Method 5005: Table III Group C (Die related tests) for class level B

		, , , , , , , , , , , , , , , , , , , ,	
Test	MIL-STD-883 method	Condition	Quantity/accept or sample size/accept
Subgroup 1			
a) Steady-state life test	1005	Test condition to be specified (1000 hours at 125°C or equivalent in accordance with table 1)	sample size number = 45, c = 0
b) End-point electrical parameters		As specified in the applicable device specification	

Method 5005: Table IV Group D (package related tests) for class level B

Motifica occo. Table IV O	Toup D (pa	ckage related tests) for class	ICVCI D
Test (1)	MIL-STD- 883 method	Condition	Quantity/accept or sample size/accept
Subgroup 1 (2)			sample size
Physical Dimensions	2016		number = 15, c = 0
Subgroup 2			
a) Lead Integrity (3)	2004	Test Condition B (lead fatigue)	sample size
b) Seal - Fine & Gross leak (5)	1014	As applicable	number = 45, c = 0
Subgroup 3 (4)			
a) Thermal Shock	1011	Test cond B as a min. 15 cycles min	sample size
b) Temp Cycle	1010	Test Condition C. 100 cycles min	number = 15, c = 0
c) Moisture resistance	1004		
d) Visual Examination		In accordance with visual criteria method 1004 and 1010	
e) Seal - Fine & Gross leak	1014	As applicable	
f) End Point Electricals		As specified in the applicable device specification	
Subgroup 4 (4)			
a) Mechanical Shock	2002	Test condition B minimum	sample size
b) Vibration, variable frequency	2007	Test condition A minimum	number = 15, c = 0
c) Constant Acceleration	2001	Test condition E minimum (Y1 only)	
d) Seal - Fine & Gross leak	1014		
e) Visual examination		In accordance with meth 1010 or 1101	
f) End point Electricals (6)		As specified in applicable device specification	
Subgroup 5 (2)			
a) Salt Atmosphere	1009	Test condition A minimum	sample size
b) Visual Examination	1014	In accordance with method 1009	number = 15, c = 0
c) Seal - Fine & Gross leak			
Subgroup 6 (2)			
a) Internal water-vapour content	1018	5000ppm max water content at 100°C	3/0 or 5/1
Subgroup 7 (2)			sample size
a) Adhesion of Lead finish (12)	2025		number = 15, c = 0
Subgroup 8 (2)			
a) Lid Torque	2024		5/0

¹⁾ In line monitor data may be substituted for subgroups D1,D2,D6,D7 and D8 upon approval by the qualifying activity. The monitors shall be performed by package type and to the specified subgroup test method.

²⁾ Electrical reject devices from the same inspection lot may be used for samples.

³⁾ The sample size number of 45, C=0 for lead integrity shall be based on the number of leads or terminals tested and shall be taken from a minimum of 3 devices.

⁴⁾ Seal tests need only be performed on packages having leads exiting through a glass seal.

⁵⁾ Devices used in subgroup 3 can be used in subgroup 4.

⁶⁾ End point electrical parameters may be performed after moisture resistance and prior to seal test.

⁷⁾ Sample size based on number of leads.

6.2 Screening Sequence for DSCC SMD listed devices

Method 5004: Table 1 Class level B screening

Screen	MIL-STD-883 method	Condition	Requirement
Internal Visual (1)	2010	Test Condition B	100%
Stabilisation Bake	1008	24hrs @ condition C minimum	100%
Temperature Cycling (2)	1010	Test Condition C	100%
Constant Acceleration	2001	Test condition E minimum	
		Y1 orientation only	100%
Visual Inspection			100%
Initial (pre-burn-in) (3)		In accordance with applicable	100%
electrical Parameters		device specification	
Burn-In Test	1015	160 hours at 125°C minimum	100%
Interim (Post Burn-In)		In accordance with applicable	100%
Electrical Parameters		device specification	
Percentage Defect Allowable			5% all lots
Final Electrical Test a) Static tests 1) 25°C subgroup 1 table 1 5005 2) Maximum and Minimum rated operating temperature subgroup 2,3 table 1 5005 b) Dynamic or functional tests 1) 25°C subgroup 4,7 table 1 5005 2) Minimum and Maximum rated operating temperature subgroup 5,6,8 table 1 5005 c) Switching tests at 25°C subgroup 9 table 1 5005		In accordance with applicable device specification	100% 100% 100% 100%
Seal (4) a) Fine b) Gross	1014		100%
Qualification or quality (5) conformance inspection test sample selection	5005	In accordance with applicable device specification	sample
External Visual	2009		100%

¹⁾ Test samples for group B, bond strength may be selected prior to or following internal visual, prior to sealing provided all other specification requirements are satisfied. Test method 2010 applies in full except when method 5004, alt 1 or 2 is in effect.

²⁾ This may be replaced with thermal shock method 1111, test condition A, minimum.

³⁾ When specified in the applicable device specification, 100% of devices shall be tested for parameters requiring deltas.

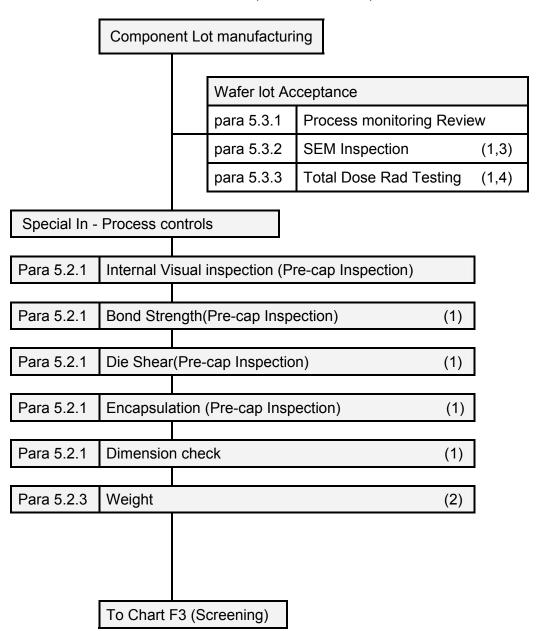
⁴⁾ Fine & Gross leak tests shall be performed separately or together between constant acceleration and external visual. All device lots having any physical processing steps performed following seal shall be retested for hermeticity and visual defects.

⁵⁾ Samples shall be selected for testing in accordance with the specific device class and lot requirement of method 5005.

7. ESA/ESCC - Space Level Product

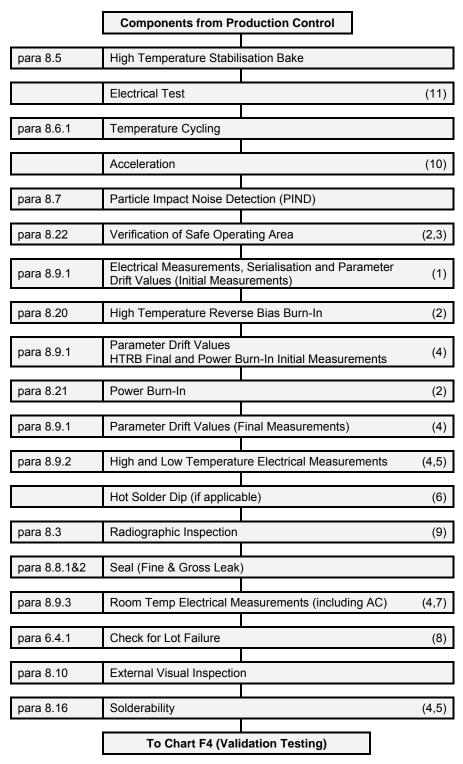
Semelab's Space Quality Level Products are based on the testing procedures specified in the generic ESCC 5000 issue 3 and in the corresponding Detail Specifications.

7.1 Chart F2 - Production Control (ESCC 5000 issue 3)



- Notes: 1) Performed on a sample basis.
 - 2) Guaranteed but not tested.
 - 3) If specified in the detail specification.
 - 4) If specified in the detail specification and required in the Purchase Order.

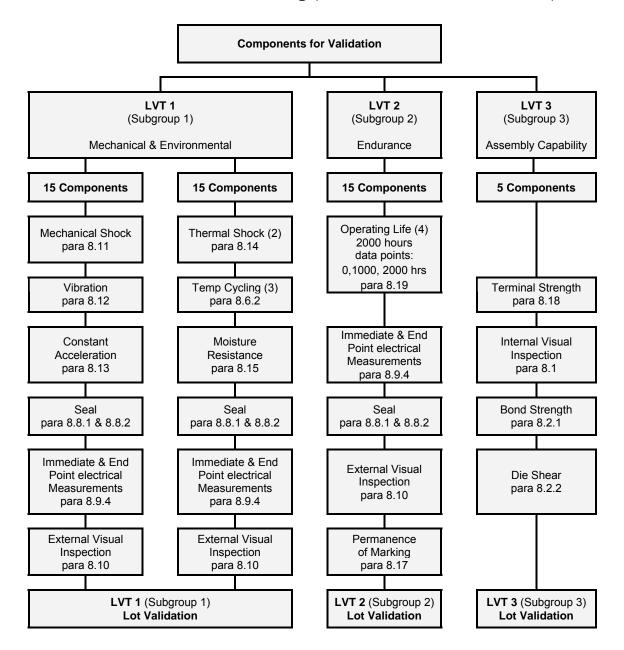
7.2 ESA/ESCC - Chart F3 Screening (ESCC 5000 issue 3)



Notes:

- 1) All components shall be serialised prior to Initial Electrical Measurement.
- 2) If specified in detail spec.
- 3) Can be performed at any time prior to initial measurements of Parametric Drift values.
- The Lot Failure criteria of paragraph 6.4 applies to this test.
- 5) Performed on a sample basis.
- 6) Can be performed at any time prior to Room Temp Electrical Measurements during screening (prior to Seal test).
- 7) Measurements of parametric Drift Values need not be repeated in Room Temperature Electrical measurements.
- 8) Check for Lot Failure shall take into account all electrical parameter failures that may occur during screening. tests in accordance with paragraph 8.9.1, 8.9.2, 8.9.3 subsequent to HTRB Burn-In.
- 9) Radiographic Inspection may be performed at any point during Screening Tests.
- 10) Not specified in ESCC 5000 iss 3, but performed by Semelab to MIL-STD-750 method 2006.
- 11) Not specified in ESCC 5000 iss 3, but performed by Semelab as a process monitor.

7.3 Chart F4 - Validation Testing (ESCC Generic Specification 5000 issue 3)



Notes:

- 1) ESCC 5000 iss 3 table F4 Qualification & Periodic Testing becomes 'Validation Testing' for non qualified parts.
- 2) Only applicable to axial diodes.
- 3) Not applicable to axial lead glass diodes.
- 4) Variance in Test method based on product type.

Ordering Information:

- 1) Order for Subgroup 1 (includes subgroups 2 & 3) requires order for 50 (30+15+5) destructive samples.
- 2) Order for Subgroup 2 (includes subgroup 3) requires order for 20 (15+5) destructive samples.
- 3) Order for Subgroup 3 requires order for 5 destructive samples.
- 4) Other Ordering Options are available please contact Semelab Sales.

8. SEMELAB IN-HOUSE processing options

In addition to the numerous qualifications held by SEMELAB, there are also other processing options available. These are based on SEMELAB's own in house specifications that have been written around a range of existing generic specifications.

These specifications enable SEMELAB to supply products processed to the requirements of original manufacturers' data sheets and military or space specifications (ie BS, CV, CECC, MIL-PRF-19500 all levels, ESA, 883B)

Before assembly of any qualified semiconductor product is started, it is essential that all the materials used in the construction of the parts be of known and proven high quality. They may be obtained from fully qualified and trusted suppliers - those with a long continuous and successful supply history. Little used or untried or suspect materials are thoroughly checked and qualified as being suitable for their intended application before assembly is allowed to start.

All products processed in this way are released in accordance with the company's Defence Standard Approvals.

8.1 CECC Processed Devices

QR208: Conformance to the requirements of CECC 50000 QR209: Screening to the requirements of CECC 50000 App VI

QR208 and QR209 are based entirely on CECC 50000 quality conformance inspection requirements and screening options.

By working to these specifications SEMELAB are able to supply full CECC "look alike" products, but released under the company's ISO9001/AQAP1 approval. Standard processing is done in accordance with Group A (electrical) and Group B (environmental) tests to full assessment level F. Group C tests and level E assessment levels are optional and are available on customer request.

Part numbers for products processed to QR208 and QR209 have -QR added (and a letter corresponding to the screening level if required). The marking for the device has the suffix '-O' added (and a letter corresponding to the screening level if screened).

Semelab are also able to process devices to existing CECC specifications where we have not undergone an approval exercise. This is particularly useful when Semelab want to supply products in a smaller volume that does not justify the cost of the full approval exercise.

Part numbers for parts processed to detailed specifications will have the suffix '-O' added to the original part number (and a letter corresponding to the screening level if required). The marking for the device has the suffix '-O' added (and a letter corresponding to the screening level if screened).

Ordering Information (when no CECC specification exists):-

Part Number	Description	Marking (*)
2N5153-QR	QR208 gps A, B level F	2N5153-O
	Processed to CECC full assessment level F, Groups A, B	
2N5153-QR-B	QR208 gps A, B level F + QR209 sequence B	2N5153-O/B
	Processed to CECC full assessment level F, Groups A, B	
	with screening in accordance with CECC 50000 App VI seq B	
2N5153-QR-EB	QR208 gps A, B level E + QR209 sequence B	2N5153-O/B
	Processed to CECC full assessment level E, Groups A, B	
	with screening in accordance with CECC 50000 App VI seq B	
2N5153-QR-EBC	QR208 gps A, B, C level E + QR209 sequence B	2N5153-O/B
	Processed to CECC full assessment level E, Groups A, B, C	
	with screening in accordance with CECC 50000 App VI seq B	

^{*} Where space permits

8.2 BS and CV Processed Devices (Bipolar)

Semelab can also provide look alike devices against BS specifications. This can be carried out against any of the BS detail device specifications, including those where the original manufacturer has ceased production. Semelab can also supply old type CV devices which have been converted into the BS system.

Product is processed to the requirements of Group A (electrical) and Group B (mechanical and environmental) tests of BS detail device specifications. Parts processed in accordance with these specifications are marked with the suffix '-O' added to the original part number.

Screening can also be carried out against the BS sequences A,B,C,D if required

Ordering Information (example):

Part Number	Description	Marking (*)
BFT69-O	Requirements of BS9365-F005 Groups A & B	BFT69-O
BFT69-O-B	Requirements of BS9365-F005 Groups A & B	BFT69-0/B
	with screening in accordance with BS sequence B	
CV7xxx-0	Requirements of BS 9300 Cxxx Groups A,B	CVxxx-O

^{*} Where space permits

8.3 MIL-PRF-19500 Processed Discrete Semiconductors

QR205: 'Mil Processed' Full Quality Conformance Inspection (MIL-PRF-19500) QR204: 'Mil Processed' Discrete Component Screening (MIL-PRF-19500)

SEMELAB's QR205 and QR204 processing specifications, in conjunction with the company's AQAP1 / ISO 9001 approval present a viable alternative to the American MIL approved parts from a European manufacturer.

Semelab QR205 (quality conformance) is based on the quality conformance inspection requirements of MIL-PRF-19500 groups A (table VI), B (table VII).

Semelab QR204 (screening options) is based on the screening options and requirements of MIL-PRF-19500 (table IV).

Full details of Semelab QR205 and QR204 are included in the following pages, showing sample sizes and test methods used.

All manufacture and processing is carried out on our approved High-Rel assembly line in our Lutterworth factory and product is released under the company's AQAP1 defence standard approval.

The table below shows part number examples and corresponding processing options and marking. The device marking will also contain the SEMELAB identifier (SML) plus the date code where space permits.

Ordering Information: (examples)

Part Number	Description	Marking (*)
2N2369-JQR	QR205 groups A,B	2N2369-JQR
2N2369-JQRB	QR205 groups A,B	2N2369-JQRB
	Screening to QR204 level B	
2N2369-JQRA	QR205 groups A,B	2N2369-JQRA
	Screening to QR204 level A	
2N2369-JQRS	Space Level – see section 8.4 (QR216 & QR217)	2N2369-JQRS
	QR217 groups A,B Screening to QR216	

^{*} Where space permits

MIL-PRF-19500 processed Discrete Semiconductors (continued)

8.3.1 'Mil Processed' Full Quality Conformance Inspection (ref: MIL-PRF-19500)

QR205: Group A - Electrical Tests

* small lot conformance

Subgroup	Description	LTPD	Sample*	Reject
1	Visual + mechanical Inspection	5	45	0
2	DC electrical tests at 25°C	5	45	0
3	DC electrical tests at maximum and minimum rated operating temperature	30	8	0
4	AC electrical tests at 25°C	30	8	0
5	Safe Operating Area (Power Transistors) a) DC b) Clamped Inductive c) Unclamped Inductive Endpoint electrical measurements	30	8	0

The specified parameters to be included in each subgroup shall be as per the detail specification. Where no parameters have been specified in a particular subgroup or test within a subgroup, no Group A testing is required for that subgroup or test to satisfy Group A requirements. A single sample may be used for all subgroup testing. These tests are considered non-destructive.

QR205: Group B - Short term Environmental & Endurance Tests * small lot conformance

Test	Note	MIL-STD-750 method	Condition	Sample*	Reject
Subgroup 1	(1)		Separate samples can be used		
Solderability	(3)	2026	for each test	4 leads	1
Resistant to solvents		1022		3 devices	
Subgroup 2					
Thermal shock (temperature cycling)		1051	No dwell is required at 25°C. Test condition C1 (25 cycles), temp extreme, ≥10 mins	6	0
hermetic seal		1071			
(a) Fine Leak			Test condition G or H. Max leak =5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for <0.3cc)		
(b) Gross leak			(5x10 dill 60/3 for 40.000)		
Electrical Measurements					
Subgroup 3	(4)				
Steady-state operation life or		1027	340hrs at specified bias	12	0
Intermittent operation life or		1037	conditions		
Blocking life					
Electrical Measurements		-	As specified		
Subgroup 4	(5)				
Internal visual design verification		2075	Visual criteria in accordance with qualified design.	1	0
Subgroup 5					
Thermal resistance		QA1023	As specified ref SEMELAB SPEC	6	0
Subgroup 6					
High temperature life (non operating)		1032	340hrs high temperature storage	12	0
Electrical Measurements			As specified		

MIL-PRF-19500 processed Discrete Semiconductors (continued)

QR205: Group C - Periodic Inspection (chargeable option on reguest) * small lot conformance

QK205. Group C -			\		conformance
Test	note	MIL-STD-750 method	Condition	Sample *	Reject
Subgroup 1					
Physical dimensions		2066	Dimensions per case outline specified	6	0
Subgroup 2					
Thermal shock (glass strain)		1056	Test condition A, except for devices > 10W at T=25which is condition B	6	0
Terminal strength		2036	As specified		
Hermetic seal (a) Fine Leak		1071	a) Test condition H. Max leak rate =5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for internal cavity <0.3cc)		
(b) Gross leak		1071	b) Test condition C		
Moisture resistance		1021	Omit initial conditioning		
Electrical Measurements			As specified		
Subgroup 3	(4)				
Shock		2016	Non-operating, 1500G, 0.5ms, 5 blows in each orientation, X1, Y1, Z1	6	0
Vibration (variable frequency)		2056			
Constant acceleration		2006	I minute min. in each orientation, X1, Y1, Z1 at 20000G min except at 10000G min if device ≥15W at T _c =25°C		
Electrical Measurements			As specified		
Subgroup 4	(1)				
Salt atmosphere (corrosion)		1041		6	0
Subgroup 5			As specified:		
Thermal Resistance				6	0
		3131	Bipolar transistors		
		3161	MOSFETS		
		3101,4081	Diodes		
Subgroup 6 Steady-state operation life or		1026	1000hrs at max operating junction temp	12	0
Intermittent operation life or		1036	As specified		
Blocking life					
Electrical Measurements					

Electrical reject devices from the same inspection lot may be used for all subgroups when electrical end point measurements are not required.

²⁾ Post burn-in electrical rejects may be used.

³⁾ The LTPD for solderability test applies to the number of leads inspected except in no case shall less than three devices be used to provide the number of leads required.

⁴⁾ If a given inspection lot undergoing Group B inspection has been selected to satisfy Group C inspection requirements, the 340 hour life test may be continued to 1000 hours in order to satisfy the Group C life test requirements. In such cases, either the 340 hour end point measurements must be made as a basis for Group B lot acceptance or the 1000 hour end point measurement shall be used as the basis for both Group B and Group C acceptance.

⁵⁾ Subgroup 4 may be omitted if the devices have been manufactured by Semelab as sample pre-cap visual inspection will have been performed.

MIL-PRF-19500 processed Discrete Semiconductors (continued)

8.3.2 'Mil Processed' Discrete Component Screening (ref: MIL-PRF-19500)

QR204: Discrete Component Screening (with reference to MIL-STD-750)

				U 1		
	Description	MIL-STD method	-750	Conditions	JQR-A	JQR-B
1	Internal Visual (Precap) Inspection	2069 2072	2070		100%	n/a
2	High temperature stabilisation bake	1032		24 hrs min at rated maximum storage temperature	100%	100%
3	Temperature Cycling	1051		20 cycles at -55°C to +175°C or max storage temp (whichever is lower) with minimum 10 minutes dwell time	100%	100%
4	Constant acceleration	2006		20,000G force in Y1axis for 1 min duration (see note 2)	100%	100%
5	Particle Impact Noise Detection (PIND)	2052				
	Hermeticity					
6	a) Fine	1071		Test condition H. Max leak rate =5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for internal cavity <0.3cc)	100%	100%
	b) Gross	1071		Condition C	100%	100%
7	Device Serialisation					
8	Interim electrical				100%	100%
	High temperature reverse bias a) Bipolar	1039		Test Condition A		
10	b) Power MOSFET	1042		Test Condition B	100%	100%
	c) Diodes	1038		Test Condition A		
11	Interim electrical			Group A (read & record)	100%	100%
	Power burn-in					
	a) Bipolar	1039		Test Condition B - 160 hrs min		
	b) Power MOSFET	1042		Test Condition A - 160 hrs min		
12	c) Diodes	1038		Test Condition B - 96 hrs min	100%	100%
	d) Case mounted	1038		Test Condition A – 48 hrs min		
	Rectifiers					
12	Final plants at			Group A	4000/	4000/
13	Final electrical			Read & Record +Drift check (1)	100%	100%
14	Radiographic tests	2076				
14	(X-Ray)	2070				

Notes:

- 1) Group A end point tests are DC functional / parametric at 25°C (subgroup 2) of QR205.
- 2) 10000G force for devices with power rating >10 watts at T_c=25°C.
 3) PDA (percentage defects allowable) is 10% between steps 9 & 11 and 11& 13.

8.4 'Space Level Processed' Discrete Semiconductors.

QR217: 'Space Level' Full Quality Conformance Inspection.

QR216: 'Space Level' Discrete Component Screening

SEMELAB's QR217 and QR216 processing specifications, in conjunction with the company's AQAP1 / ISO 9001 approval present a viable alternative to American MIL-PRF-19500 space level parts supplied from a European manufacturer and ESA / ESCC 5000 space level parts.

QR217 (quality conformance) is based on the quality conformance inspection requirements of MIL-PRF-19500 groups A (table V), B (table VIa), C (table VII) and ESA / ESCC 5000 (chart F4) lot validation tests.

QR216 (screening) is based on the screening requirements of MIL-PRF-19500 (table IV) and ESA /ESCC 5000 (chart F3)

Details of QR217 and QR216 are included in the following pages.

All manufacture and processing is carried out on our approved High-Rel assembly line in our Lutterworth factory and product is released under our AQAP1 defence standard approval.

The 'standard' JQRS part is processed to the Semelab data sheet, screened to QR216 and has conformance testing to Q217 groups A and B. Additional options are available as shown below. These are chargeable and must be specified at order stage. The extensions on the Semelab part numbers used reflect these additional items.

Additional options available:

1) Customer Pre-Cap visual Inspection	(suffix P)
2) Data Pack supplied	(suffix D)
3) Group C tests	(suffix C)

Ordering Information: (examples)

Part Number	Description	Marking (*)
2N2369-JQRS	QR217 groups A,B Screening to QR216	2N2369-JQRS
2N2369-JQRS -C	QR217 groups A,B and group C. Screening to QR216	2N2369-JQRS
2N2369-JQRS -CD	QR217 groups A,B and group C. Screening to QR216	2N2369-JQRS
	with Data Pack	
2N2369-JQRS-PCD	QR217 groups A,B and group C. Screening to QR216	2N2369-JQRS
	with Customer Pre-cap Visual Inspection & Data Pack	

* Where space permits

Notes

- 'Additional Options' (Customer Pre-Cap Visual Inspection, Group C's, Datapack) are chargeable and must be specified at order stage.
- 2) 'Additional Options' are reflected in the Semelab Part Number, but do not affect device marking.

8.4.1 QR217 'Space Level' Full Quality Conformance Inspection.

QR217: Group A - Electrical Tests

* small lot conformance

Subgroup	Description	Sample*	Reject
1	Visual + mechanical Inspection	20	0
2	DC electrical tests at 25°C	20	0
3	DC electrical tests at maximum and minimum rated operating temperature	8	0
4	AC electrical tests at 25°C	8	0
5	Safe Operating Area (Power Transistors)	8	0
	Endpoint electrical measurements		

The specified parameters to be included in each subgroup shall be as per the Semelab Data Sheet. Where no parameters have been specified in a particular subgroup or test within a subgroup, no Group A testing is required for that subgroup or test to satisfy Group A requirements. A single sample may be used for all subgroup testing. These tests are considered non-destructive.

QR217: Group B - Short term Environmental & Endurance Tests * small lot conformance

Test	note	MIL-STD-750 method	Condition	Sample*	Reject
Subgroup 1					
Physical Dimensions		2066	As per specification	8	0
Subgroup 2					
Solderability	(3)	2026	Separate samples can be used for	6 devices	0
Resistant to solvents	(3)	1022	each test		
Subgroup 3 Thermal shock (temperature cycling)		1051	No dwell is required at 25°C. Test condition C1 (25 cycles), temp extreme, ≥10 mins (100 cycles covered by MIL883	6	0
hermetic seal			group D programme)		
(a) Fine Leak (b) Gross leak		1071	Test condition G or H. Max leak =5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for <0.3cc)		
Electrical Measurements					
Subgroup 4 Steady-state operation life or Intermittent operation life	(4)	1027	340hrs at specified bias conditions	12	0
or Blocking life Electrical Measurements		1037	As specified		
Internal visual design verification		2075	Visual criteria in accordance with qualified design.	5	0
bond strength		2037		11 wires	0
Subgroup 5					
Thermal resistance		QA1023	As specified - SEMELAB SPEC	6	0
Subgroup 6					
High temperature life (non operating)		1032	340hrs high temperature storage	12	0
Electrical Measurements			As specified		

See notes at bottom of group C table.

QR217: Group C - Periodic Inspection (chargeable option on request) * small lot conformance

Test note method method method Condition Sample * Reject Subgroup 1 Physical dimensions 2066 Dimensions per case outline specified 6 0 Subgroup 2 & 3 Thermal shock (glass strain) 1056 Test condition A, except for devices > 10W at T=25 which is condition B 6 0 Shock 2016 Non-operating, 1500G, 0.5ms, 5 blows in each orientation, X1, Y1, Z1 6 0 Vibration (variable frequency) 2056 1 minute min. in each orientation, X1, Y1, Z1 4 2000/20 min except at 10000G min if device ≥15W at T _u =25°C 4 2000/20 min except at 10000G min if device ≥15W at T _u =25°C 4 2000/20 min except at 10000G min if device ≥15W at T _u =25°C 4 4 2000/20 min except at 10000G min if device ≥15W at T _u =25°C 4 4 4 2000/20 min except at 10000G min if device ≥15W at T _u =25°C 4 4 4 1071 a) Test condition H. Max leak rate =5x10° atm cx/s (6x10° at	GIVETT: Cloup o	I CIII	Juic mapec	(chargeable option on request)	Siliali lot t	conformance
Physical dimensions 2066 Dimensions per case outline specified 6 0 Subgroup 2 & 3 Thermal shock (glass strain) 1056 Test condition A, except for devices > 10W at T=25 which is condition B 6 0 Shock 2016 Non-operating, 1500G, 0.5ms, 5 blows in each orientation, X1, Y1, Z1 6 0 Vibration (variable frequency) Constant acceleration 2056 1 minute min. in each orientation Y1 at 20000G min if device ≥15W at T _c =25°C 20000G min except at 10000G min if device ≥15W at T _c =25°C Hermetic seal (a) Fine Leak 1071 a) Test condition H. Max leak rate =5x.0° atm cc/s (5x10° atm cc/s for internal cavity <0.3cc) b) Test condition C (b) Gross leak 1071 b) Test condition C Omit initial conditioning Moisture resistance 1021 Omit initial conditioning Electrical Measurements As specified Subgroup 4 (corrosion) (2) As specified: Subgroup 5 Thermal Resistance 3131 3101,4081 Bipolar transistors 3101,4081 6 0 Subgroup 6 Steady-state op lifen life or Intermittent operation life or Or Intermittent operation life or Blocking life (4) As specified Subgroup 7 (2) <td>Test</td> <td>note</td> <td></td> <td>Condition</td> <td>Sample *</td> <td>Reject</td>	Test	note		Condition	Sample *	Reject
Subgroup 2 & 3 Thermal shock (glass strain) 1056 Test condition A, except for devices > 10W at T=25 which is condition B 6 0 Shock 2016 Non-operating, 1500g, 0.5ms, 5 blows in each orientation, X1, Y1, Z1 6 0 Vibration (variable frequency) 2056 1 minute min. in each orientation Y1 at 20000G min except at 10000G min if device ≥15W at T,=25°C 1 minute min. in each orientation Y1 at 20000G min if device ≥15W at T,=25°C Hermetic seal (a) Fine Leak 1071 a) Test condition H. Max leak rate =55x10³ atm cc/s, (6x10⁻³ atm cc/s for internal cavity <0.3cc)	Subgroup 1					
Thermal shock (glass strain) Shock 2016 Non-operating, 1500G, 0.5ms, 5 blows in each orientation, X1, Y1, Z1 Vibration (variable frequency) Constant acceleration 2006 Test condition A, except for devices > 10W at T=25 which is condition B Non-operating, 1500G, 0.5ms, 5 blows in each orientation, X1, Y1, Z1 Vibration (variable frequency) Constant acceleration 2006 I minute min. in each orientation Y1 at 20000G min if device ≥15W at T _c =25°C Hermetic seal (a) Fine Leak 1071 a) Test condition H. Max leak rate =5x10° atm cc/s for internal cavity <0.3cc) b) Test condition C Moisture resistance 1021 Omit initial conditioning As specified Lectrical Measurements As specified Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance 1041 Covered by MIL883 ongoing group D programme As specified: Bipolar transistors Bipolar transistors 3131 3161 MOSFETS Diodes Subgroup 6 Steady-state op lifen life or Intermittent operation life or Intermit	Physical dimensions		2066	Dimensions per case outline specified	6	0
Shock 2016 Non-operating, 1500G, 0.5ms, 5 blows in each orientation, X1, Y1, Z1	Subgroup 2 & 3					
Vibration (variable frequency) Constant acceleration 2056 1 minute min. in each orientation Y1 at 20000G min except at 10000G min if device ≥15W at T _c =25°C Hermetic seal (a) Fine Leak 1071 a) Test condition H. Max leak rate = 5x10° atm cc/s. (5x10° atm cc/s for internal cavity <0.3cc) (b) Gross leak 1071 b) Test condition C Moisture resistance 1021 Omit initial conditioning As specified Electrical Measurements Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance 3131 3161 3101,4081 Diodes Subgroup 6 Steady-state op lifen life or Intermittent operation life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2)			1056		6	0
(variable frequency) 2006 1 minute min. in each orientation Y1 at 20000G min if device ≥ 15W at T _c =25°C Hermetic seal (a) Fine Leak 1071 a) Test condition H. Max leak rate = 5x10°3 atm cc/s. (5x10° atm cc/s for internal cavity <0.3cc)	Shock		2016			
Hermetic seal (a) Fine Leak 1071 a) Test condition H. Max leak rate =5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for internal cavity <0.3cc) (b) Gross leak 1071 b) Test condition C Moisture resistance 1021 Comit initial conditioning As specified As specified Electrical Measurements Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance 3131 3161 3161 3161 3101,4081 Diodes Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements As specified 1000hrs at max operating junction temp 12 0 As specified 1036 As specified 1000hrs at max operating junction temp 12 0 As specified			2056			
(a) Fine Leak 1071 a) Test condition H. Max leak rate =5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for internal cavity <0.3cc) (b) Gross leak 1071 b) Test condition C Moisture resistance 1021 Omit initial conditioning As specified As specified Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance 3131 3161 3161 3101,4081 Subgroup 6 Steady-state op lifen life or Blocking life Electrical Measurements Subgroup 7 (2) As specified: 1000hrs at max operating junction temp As specified 1000hrs at max operating junction temp As specified 1000hrs at max operating junction temp 12 0	Constant acceleration		2006	20000G min except at 10000G min if		
Moisture resistance Terminal strength Electrical Measurements Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2) Omit initial conditioning As specified As specified Covered by MIL883 ongoing group D programme As specified: Bipolar transistors MOSFETS J1041 1026 1000hrs at max operating junction temp 12 O As specified 1036 As specified Subgroup 6 Steady-state op lifen life or Blocking life Electrical Measurements Subgroup 7 (2)			1071	=5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for		
Terminal strength As specified As specified Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance 3131 Bipolar transistors Bipolar transistors 3161 MOSFETS Jindep 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2) As specified Covered by MIL883 ongoing 6 0 group D programme As specified: Bipolar transistors 6 0 1000hrs at max operating junction temp 12 0 As specified As specified Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2)	(b) Gross leak		1071	b) Test condition C		
Electrical Measurements Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements As specified Covered by MIL883 ongoing goup D programme As specified: As specified: As specified: MOSFETS 3101,4081 Diodes 1000hrs at max operating junction temp 12 0 As specified As specified: 1000hrs at max operating junction temp 12 0 As specified	Moisture resistance		1021	Omit initial conditioning		
Subgroup 4 Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2) 1041 Covered by MIL883 ongoing group D programme As specified: Bipolar transistors As specified: MOSFETS 3101,4081 Diodes 1026 1000hrs at max operating junction temp or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2)	Terminal strength			As specified		
Salt atmosphere (corrosion) Subgroup 5 Thermal Resistance Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 1041 Covered by MIL883 ongoing group D programme As specified: Bipolar transistors Bipolar transitors Bipolar tr	Electrical Measurements			As specified		
(corrosion) Subgroup 5 Thermal Resistance 3131 Bipolar transistors 6 0 MOSFETS 3101,4081 Diodes Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2) As specified: As specified: As specified: As specified: As specified: As specified: 1000hrs at max operating junction temp 12 0 As specified	Subgroup 4	(2)				
Subgroup 5 Thermal Resistance 3131 Bipolar transistors 6 0 MOSFETS Jinders Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2) As specified: As specified: As specified: As specified: As specified: As specified: 1000hrs at max operating junction temp 12 0 As specified			1041	Covered by MIL883 ongoing	6	0
Thermal Resistance 3131 Bipolar transistors 6 0 Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 (2)	(corrosion)			group D programme		
Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements MOSFETS Diodes 1000hrs at max operating junction temp As specified 1036 As specified	Subgroup 5			As specified:		
Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements Subgroup 7 Capable 3101,4081 Diodes 1000hrs at max operating junction temp 12 As specified As specified	Thermal Resistance		3131	Bipolar transistors	6	0
Subgroup 6 Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements (4) 1026 1000hrs at max operating junction temp 12 0 As specified Subgroup 7 (2)			3161	MOSFETS		
Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements 1026 1000hrs at max operating junction temp 12 0 As specified Subgroup 7 (2)			3101,4081	Diodes		
Steady-state op lifen life or Intermittent operation life or Blocking life Electrical Measurements 1026 1026 1000hrs at max operating junction temp of As specified As specified Subgroup 7 (2)	Subgroup 6	(4)				
or Blocking life Electrical Measurements Subgroup 7 (2) As specified (As specified)	Steady-state op lifen life or		1026	1000hrs at max operating junction temp	12	0
Electrical Measurements Subgroup 7 (2)	or		1036	As specified		
Subgroup 7 (2)	•					
	Electrical Measurements					
Internal Water Vapour Covered by MIL883B ongoing 3 0	Subgroup 7	(2)				
	Internal Water Vapour			Covered by MIL883B ongoing	3	0
Group D programme				Group D programme		

¹⁾ Individual subgroups may be performed on representative parts from the same package family.

Electrical reject devices from the same inspection lot may be used for all subgroups when electrical end point measurements are not required.

³⁾ Post burn-in electrical rejects may be used.

⁴⁾ If a given inspection lot undergoing Group B inspection has been selected to satisfy Group C inspection requirements, the 340 hour life test may be continued to 1000 hours in order to satisfy the Group C life test requirements. In such cases, either the 340 hour end point measurements must be made as a basis for Group B lot acceptance or the 1000 hour end point measurement shall be used as the basis for both Group B and Group C acceptance.

8.4.2 QR216: 'Space Level' Discrete Component Screening

QR216: Discrete Component Screening (with reference to MIL-STD-750)

			illing (with reference to MIL-31D-730)	
	Description	MIL-STD-750 method	Conditions	JQR-S
1	Internal Visual (Pre-cap) Inspection	2069, 2070 2072		100%
2	Customer Pre Cap Visual Inspection	2069, 2070 2072	Customer specified option (chargeable)	100%
3	High temperature stabilisation bake	1032	24 hrs min at rated maximum storage temperature	100%
4	Temperature Cycling	1051	20 cycles at -55°C to +175°C or max storage temp (whichever is lower) with minimum 10 minutes dwell time	100%
5	Constant acceleration	2006	20,000G force in Y1axis for 1 min duration (see note 2)	100%
6	Particle Impact Noise Detection (PIND)	2052	(full yielded quantity)	100%
7	Device Serialisation			
8	Interim electrical		Read & Record	100%
	High temperature reverse bias			
9	a) Bipolar	1039	Test Condition A	
	b) Power MOSFET	1042	Test Condition B	100%
	c) Diodes	1038	Test Condition A	
10	Interim electrical (note 3)		Read & Record, Drift Check	100%
	Power burn-in			
	a) Bipolar	1039	Test Condition B - 240 hrs min	
11	b) Power MOSFET	1042	Test Condition A - 240 hrs min	100%
	c) Diodes	1038	Test Condition B - 240 hrs min	
12	Final electricals (note 3)		Read & Record, Drift check (1)	100%
13	a) Hermeticity - Fine	1071	Test condition H. Max leak rate =5x10 ⁻⁸ atm cc/s, (5x10 ⁻⁷ atm cc/s for internal cavity <0.3cc)	100%
	b) Hermeticity - Gross	1071	Condition C	100%
14	Radiographic tests (X-Ray)	2076	(May be performed at any time after serialization)	100%
15	External Visual Inspection	2071		

Notes:

- 1) Group A end point tests are DC functional / parametric at 25°C (subgroup 2) of QR217. 2) 10000G force for devices with power rating >10 watts at T_c =25°C. 3) PDA (percentage defects allowable) is 10% between steps 8 & 10 and 10 & 12.

8.4.3 Comparison of Space Level die lot approval procedures.

The table below shows a comparison of operations carried out for die approval within the generic approval systems (MIL-PRF-19500 space level and ESA / ESCC 5000. It must be noted that SEM and RHA total dose evaluation are options only available within MIL-PRF-19500 and ESA / ESCC 5000. SEM and RHA total dose evaluation are not available within the Semelab JQR-S processing options. If SEM and/or RHA total dose evaluation are required then the ESE / ESCC 5000 procedures must be followed – see section 7 – ESA / ESCC Space level products.

Space Level/ Die Lot Acceptance Table

	GEN	ERIC	SML
Die Lot Acceptance	ESCC	JANS	JQR-S
Selected Wafer	•	•	•
Probe Test (100%)	•	•	•
Glassivation / Metalisation Inspection	•	•	•
Visual Inspection (100%)	•	•	•
Sample Assembly (10 pcs)	•	•	•
Stabilization	•	•	•
Temperature Cycling	•	•	•
Electrical Test (read/record)	•	•	•
HTRB	•	•	•
Electrical Test (read/record)	•	•	•
Steady State Life (1000 hrs)	•	•	•
Electrical Test (read/record)	•	•	•
Wire Bond Evaluation	•	•	•
Die Shear Evaluation	•	•	•
SEM	OPT	OPT	-
RHA Total Dose Evaluation	OPT	OPT	-

Die Lot Acceptance Table

8.5 'MIL883B Processed' Integrated Circuits

QR215: 'MIL Processed /883B' Full Quality Conformance Inspection for Linear Integrated Circuits A and B, C and D optional)

QR214: 'MIL Processed /883B' Linear Integrated Circuit Component Screening

Semelab's QR214 and QR215 are based on MIL-STD-883E, METHOD 5005 quality conformance, inspection requirements and METHOD 5004 screening methods.

Semelab QR215 (quality conformance) covers the control procedures for group A (electrical), group B (environmental), group C (die related) and group D (package related) tests. It is based on METHOD 5005 conformance procedures and MIL-STD-883E test methods

Semelab QR214 (screening) is based on METHOD 5004 screening procedures and MIL-STD-883E test methods.

Ordering Information:

Devices screened in accordance with Semelab QR214 and QR215 are identified using the standard product part number with the addition of the suffix "–8QRB".

Example: LM117H built and screened to the MIL883B flows Method 5005 and Method 5004 in accordance with QR214 and QR215 is: LM117H-8QRB

Device Marking:-

xxx-8QRB for products equivalent to MIL883B parts - e.g. LM117H-8QRB + SML + DC

8.6 Customer Specifications

SEMELAB is also able to offer release on all parts manufactured in accordance with customers own 'in-house' or national specifications. Both lot acceptance and screening options can be met. Manufacturing is carried out to many customers' special requirements for the UK, Europe, USA and elsewhere.

Ordering Information:-

Customer part number and specification

8.7 Data Sheets

Many products can be processed in accordance with the original manufacturer's data sheets (JEDEC or PRO-ELETRON registered). Product can be supplied with fully traceable Certificate of Conformity under SEMELAB's company AQAP1 / ISO 9001 approval. This can be also be done in cases where the original supplier has ceased production.

Ordering Information:-

2N5000 with AQAP1 / ISO 9001 release ordered as follows: 2N5000.MOD

9. Comparison of Screening Options (Discrete Devices)

9.1 Comparison of High-Rel Screening Options (Discrete Devices)

The table below shows the comparison of screening options available within the CECC, BS and MIL approvals. Comparison is also shown with Semelab's in-house QR204 options.

	CI	ECC/	QR2	09		BS 9300				204	MIL		
	Α	В	С	D	Α	В	С	D	JQRA	JQRB	JAN* TXV	JAN*	
Pre-cap Visual	•				•	•			•		•		
High Temp Storage	•	•	•		•	•	•		•	•	•	•	
Temperature Cycle	5 cycles	5 cycles	5 cycles		10 cycles	10 cycles	10 cycles		20 cycles	20 cycles	20 cycles	20 cycles	
Constant Acceleration	•	•	•		•	•	•		•	•	•	•	
Particle impact noise detection (PIND)													
Fine Leak test	•	•	•		•	•	•		•	•	•	•	
Gross Leak Test	•	•	•		•	•	•		•	•	•	•	
Device Serialisation													
Variables Electrical test	•				•				±	±	±	±	
Attributes Electrical tests		•		•		•	•	•	•	•	•	•	
Burn-In (HTRB)	168 hrs*	72 hrs*		48 hrs*	160 hrs*	72 hrs*	48 hrs*	48 hrs*	0	0	0	0	
Variables Electrical test									±	±	±	±	
Attributes Electrical tests									•	•	•	•	
Burn-In (Power)	168 hrs*	72 hrs*		48 hrs*	160 hrs*	72 hrs*	48 hrs*	48 hrs*	160 hrs	160 hrs	160 hrs	160 hrs	
Variables Electrical test	•				•				±	<u>±</u>	±	±	
Attributes Electrical tests		•	•	•		•	•	•	•	•	•	•	
Radiographic tests					•								

- Test Performed
- ± Test Performed if required by device detail specification
- O 24 hours for PNP devices. 48 hours for NPN devices
- High Temp Reverse Bias for Case rated devices
 Power Burn-in for Ambient rated Devices

CECC / QR209 : Screening carried out in accordance with CECC 50000 Appendix 6

BS : Screening carried out in accordance with BS9300 section 1.2.10

QR216 : Screening carried out in accordance with Semelab QR216

QR204 : Screening carried out in accordance with Semelab QR204

MIL : Screening carried out in accordance with MIL-PRF-19500 (Table 2)

 * full JANTX, JANTXV not available from Semelab

Comparison of Screening Options (Discrete Devices) (continued)

9.2 Comparison of Space Level Screening Options

Space Level Flow Comparison Table	GENE	RIC	QR216
Screening	ESCC	JANS*	JQRS
Pre-cap Visual	•	•	•
Customer pre-cap Visual	OPT	OPT	OPT
High Temp Storage (Stabilization Bake)	24 hrs	24 hrs	24hrs
Temperature cycling	20 cycles	20 cycles	20 cycles
Thermal impedance	OPT	0	•
Constant Acceleration	•	•	•
PIND	•	•	•
Fine/Gross Leak	•	•	•
Serialization	•	•	•
Interim Electrical Measurements	-	-	-
Interim Electrical Measurements (Read and Record / Drift)	•	•	•
HTRB	•	•	•
Electrical Measurements	-	-	-
Parametric Drift measurements (Read and Record / Drift)	•	•	•
Burn-In	min 168 hrs max 264 hrs	240 hrs	240hrs
Electrical Measurements	-	-	-
Parameter Drift Measurements (Read and Record)	•	•	•
PDA Calculations	•	•	•
Read and Record Test Data	•	•	•
Other Electrical Parameters (Temp, Dynamic)	•	•	•
Fine/Gross Leak	•	•	•
Radiography	•	•	•
External Visual Inspection	•	•	•

*JANS part not available from Semelab.

Notes: O if specified in detail specification.

■ not specified in ESCC 5000 iss 3, but performed by Semelab.



Homepage

Divisions

Technologies

Search Tools

Resources

Corporate

Part number search for devices beginning "IRF9130SMD05DSG"

Semelab Home

Datasheets are downloaded as Acrobat PDF files.





Fet Devices

PRODUCT	Status	Screening options available	Polarity	Package	V _{DSS} (V)	I _{D(cont)} (A)				Q _G (nC)
IRF9130SMD05DSG	•	✓	P-Channel	SMD0.5 (TO276AA)	100V	11A	45W	0.3Ω	860pF	29nC

SCREENING OPTIONS AVAILABILITY

(including CECC, MIL-PRF-19500, BS)

symbol indicates that screening options are available for this device.

For device-specific screening options and order information, click the relevant symbol.

For more information on Screening options, visit the Screening Homepage.

Top of Page

If you are unable to find a suitable part, please contact us.





Homepage Divisions

Technologies

Search Tools

Resources

Corporate

Part number search for devices beginning "IRF9130SMD05"

Semelab Home

Datasheets are downloaded as Acrobat PDF files.





Fet Devices

PRODUCT	Status	Screening options available	Polarity	Package	V _{DSS} (V)	I _{D(cont)} (A)	P _D (W)	R _{DSS} (Ω)	C _{ISS} (pF)	Q _G (nC)
IRF9130SMD05	•	✓	P-Channel	SMD0.5 (TO276AA)	100V	11A	45W	0.3Ω	860pF	29nC
IRF9130SMD05DGS	•	✓	P-Channel	SMD0.5 (TO276AA)	100V	11A	45W	0.3Ω	860pF	29nC
IRF9130SMD05DSG	•	✓	P-Channel	SMD0.5 (TO276AA)	100V	11A	45W	0.3Ω	860pF	29nC

SCREENING OPTIONS AVAILABILITY

(including CECC, MIL-PRF-19500, BS)

 \checkmark symbol indicates that screening options are available for this device.

For device-specific screening options and order information, click the relevant \checkmark symbol.

For more information on Screening options, visit the Screening Homepage.

Top of Page

If you are unable to find a suitable part, please contact us.

